## MA3DF47

### Silicon mesa type

For high frequency rectification For plasma display panel drive

#### ■ Features

- Super high speed switching characteristic ( $t_{rr} = 13$  ns typ.)
- Soft recovery

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Repetitive peak reverse voltage	V <sub>RRM</sub>	370	V	
Non-repetitive peak reverse surge voltage *1	V <sub>RSM</sub>	460	V	
Forward current (Average) *2	I <sub>F(AV)</sub>	20	A	
Repetitive peak forward current *3	I <sub>FRM</sub>	150	A	
Non-repetitive peak forward surge current *4	$I_{FSM}$	100	A	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	T <sub>stg</sub>	-40 to +150	°C	

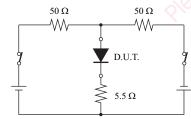
Note) \*1: 60 Hz half-sine wave. (If repeative, RMS voltage < 370 V)

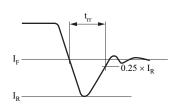
- \*2:  $T_C = 25^{\circ}C$
- \*3: Pulse width  $< 10 \mu s$ . Peak value of the sine wave. (If repeative, RMS current < 20 A)
- \*4: 50 Hz sine wave 1 cycle (Non-repetitive peak current)

#### ■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

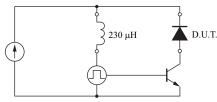
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\rm F}$	$I_F = 20 A$	6 'Ye	1.65	1.85	V
Reverse current	$I_{RRM}$	$V_{RRM} = 370 \text{ V}$			10	μΑ
Reverse recovery time *	t <sub>rr</sub> *1	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		13	20	ns
	t <sub>rr</sub> *2	$I_F = 40 \text{ A}, \text{ di/dt} = -200 \text{ A/\mus}, I_{rr} = I_R \times 0.5 \text{ A}$	Silve	25	30	
Thermal resistance (j-c)	R <sub>th(j-c)</sub>	1911, 912, 72, 215			3.0	°C/W
Thermal resistance (j-a)	$R_{th(j-a)}$	y will die			63	°C/W

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. Absolute frequency of input and output is  $10\ MHz$
  - 3. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 4. \*1: R-loadt<sub>rr</sub> measurement circuit





\*2: L-loadt<sub>rr</sub> measurement circuit



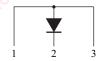
#### ■ Package

Code

TO-220D-A1

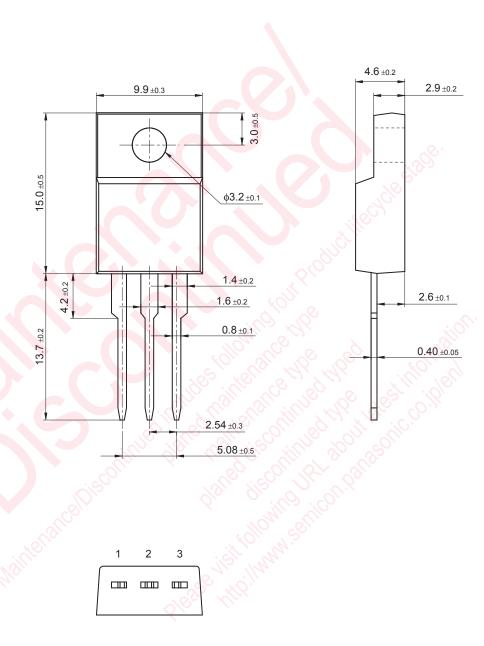
- Pin Name
  - 1: Anode
  - 2: Cathode
  - 3: Anode
- Marking Symbol: MA3DF47

#### ■ Internal Connection



TO-220D-A1

Unit: mm



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